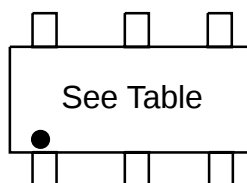
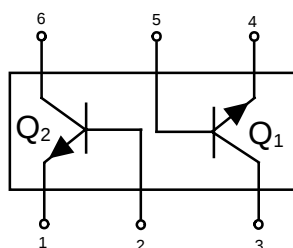


# Dual General Purpose Transistors

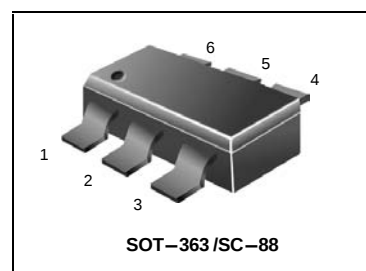
## NPN Duals

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-363/SC-88 which is designed for low power surface mount applications.

We declare that the material of product compliance with RoHS requirements.



**LBC846ADW1T1G**  
**LBC846BDW1T1G**  
**LBC847BDW1T1G**  
**LBC847CDW1T1G**  
**LBC848BDW1T1G**  
**LBC848CDW1T1G**



## MAXIMUM RATINGS

| Rating                        | Symbol    | BC846 | BC847 | BC848 | Unit |
|-------------------------------|-----------|-------|-------|-------|------|
| Collector-Emitter Voltage     | $V_{CEO}$ | 65    | 45    | 30    | V    |
| Collector-Base Voltage        | $V_{CBO}$ | 80    | 50    | 30    | V    |
| Emitter-Base Voltage          | $V_{EBO}$ | 6.0   | 6.0   | 5.0   | V    |
| Collector Current –Continuous | $I_C$     | 100   | 100   | 100   | mAdc |

## THERMAL CHARACTERISTICS

| Characteristic                           | Symbol          | Max         | Unit                 |
|------------------------------------------|-----------------|-------------|----------------------|
| Total Device Dissipation                 | $P_D$           | 380         | mW                   |
| Per Device                               |                 | 250         | mW                   |
| FR-5 Board, (1) $T_A = 25^\circ\text{C}$ |                 |             |                      |
| Derate above $25^\circ\text{C}$          |                 | 3.0         | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient  | $R_{\theta JA}$ | 328         | $^\circ\text{C/W}$   |
| Junction and Storage Temperature         | $T_J, T_{stg}$  | -55 to +150 | $^\circ\text{C}$     |

1. FR-5 = 1.0 x 0.75 x 0.062 in.

## ORDERING INFORMATION

| Device        | Marking | Shipping         |
|---------------|---------|------------------|
| LBC846ADW1T1G | 1A      | 3000 Units/Reel  |
| LBC846ADW1T3G | 1A      | 10000 Units/Reel |
| LBC846BDW1T1G | 1B      | 3000 Units/Reel  |
| LBC846BDW1T3G | 1B      | 10000 Units/Reel |
| LBC847BDW1T1G | 1F      | 3000 Units/Reel  |
| LBC847BDW1T3G | 1F      | 10000 Units/Reel |
| LBC847CDW1T1G | 1G      | 3000 Units/Reel  |
| LBC847CDW1T3G | 1G      | 10000 Units/Reel |
| LBC848BDW1T1G | 1K      | 3000 Units/Reel  |
| LBC848BDW1T3G | 1K      | 10000 Units/Reel |
| LBC848CDW1T1G | 1L      | 3000 Units/Reel  |
| LBC848CDW1T3G | 1L      | 10000 Units/Reel |

## LBC846ADW1T1G Series

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic                                                                          | Symbol        | Min | Typ | Max | Unit          |
|-----------------------------------------------------------------------------------------|---------------|-----|-----|-----|---------------|
| <b>OFF CHARACTERISTICS</b>                                                              |               |     |     |     |               |
| Collector–Emitter Breakdown Voltage<br>( $I_C = 10\text{ mA}$ )                         | $V_{(BR)CEO}$ |     |     |     | V             |
| LBC846 Series                                                                           |               | 65  | —   | —   |               |
| LBC847 Series                                                                           |               | 45  | —   | —   |               |
| LBC848 Series                                                                           |               | 30  | —   | —   |               |
| Collector–Emitter Breakdown Voltage<br>( $I_C = 10\text{ }\mu\text{A}$ , $V_{EB} = 0$ ) | $V_{(BR)CES}$ |     |     |     | V             |
| LBC846 Series                                                                           |               | 80  | —   | —   |               |
| LBC847 Series                                                                           |               | 50  | —   | —   |               |
| LBC848 Series                                                                           |               | 30  | —   | —   |               |
| Collector–Base Breakdown Voltage<br>( $I_C = 10\text{ }\mu\text{A}$ )                   | $V_{(BR)CBO}$ |     |     |     | V             |
| LBC846 Series                                                                           |               | 80  | —   | —   |               |
| LBC847 Series                                                                           |               | 50  | —   | —   |               |
| LBC848 Series                                                                           |               | 30  | —   | —   |               |
| Emitter–Base Breakdown Voltage<br>( $I_E = 1.0\text{ }\mu\text{A}$ )                    | $V_{(BR)EBO}$ |     |     |     | V             |
| LBC846 Series                                                                           |               | 6.0 | —   | —   |               |
| LBC847 Series                                                                           |               | 6.0 | —   | —   |               |
| LBC848 Series                                                                           |               | 5.0 | —   | —   |               |
| Collector Cutoff Current<br>( $V_{CB} = 30\text{ V}$ )                                  | $I_{CBO}$     | —   | —   | 15  | nA            |
| ( $V_{CB} = 30\text{ V}$ , $T_A = 150^\circ\text{C}$ )                                  |               | —   | —   | 5.0 | $\mu\text{A}$ |

### ON CHARACTERISTICS

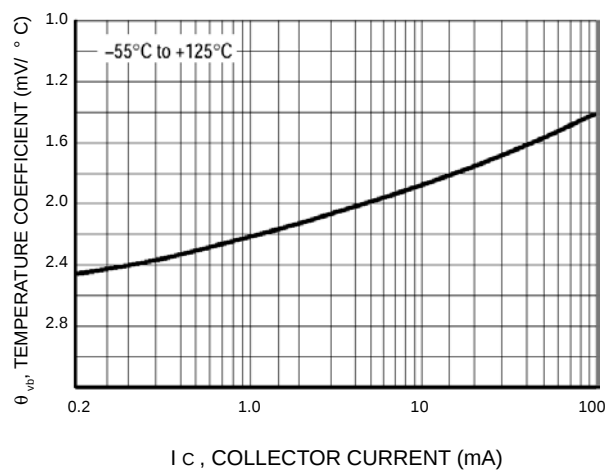
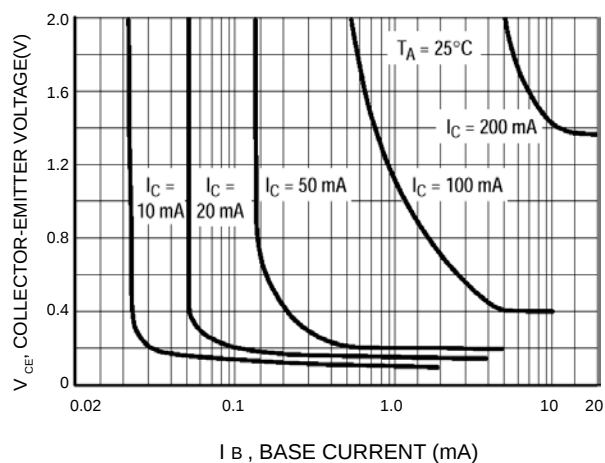
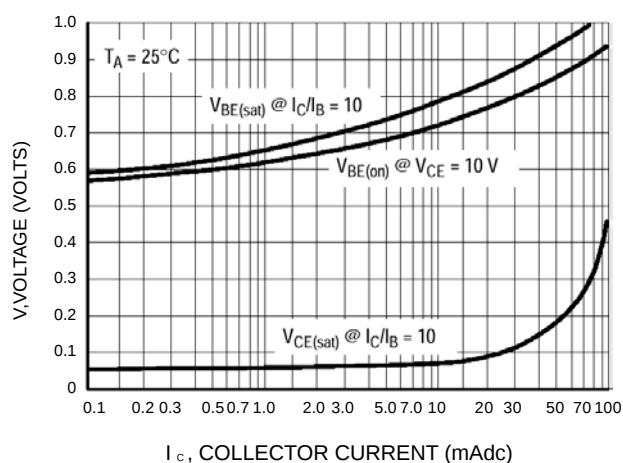
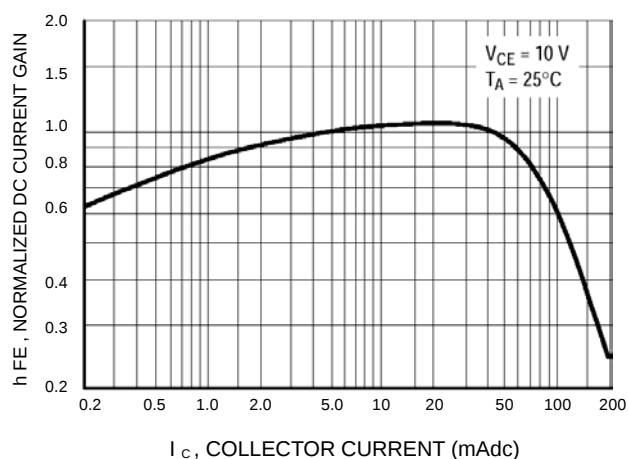
|                                                                                       |               |     |     |      |    |
|---------------------------------------------------------------------------------------|---------------|-----|-----|------|----|
| DC Current Gain                                                                       | $h_{FE}$      |     |     |      | —  |
| ( $I_C = 2.0\text{ mA}$ , $V_{CE} = 5.0\text{ V}$ )                                   |               |     |     |      |    |
| LBC846A                                                                               |               | 110 | 180 | 220  |    |
| LBC846B, LBC847B, LBC848B                                                             |               | 200 | 290 | 450  |    |
| LBC847C, LBC848C                                                                      |               | 420 | 520 | 800  |    |
| Collector–Emitter Saturation Voltage ( $I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$ ) | $V_{CE(sat)}$ | —   | —   | 0.25 | V  |
| ( $I_C = 100\text{ mA}$ , $I_B = 5.0\text{ mA}$ )                                     |               | —   | —   | 0.6  |    |
| Base–Emitter Saturation Voltage ( $I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$ )      | $V_{BE(sat)}$ | —   | 0.7 | —    | V  |
| ( $I_C = 100\text{ mA}$ , $I_B = 5.0\text{ mA}$ )                                     |               | —   | 0.9 | —    |    |
| Base–Emitter Voltage ( $I_C = 2.0\text{ mA}$ , $V_{CE} = 5.0\text{ V}$ )              | $V_{BE(on)}$  | 580 | 660 | 700  | mV |
| ( $I_C = 10\text{ mA}$ , $V_{CE} = 5.0\text{ V}$ )                                    |               | —   | —   | 770  |    |

### SMALL–SIGNAL CHARACTERISTICS

|                                                                                                                                                     |           |     |   |     |     |
|-----------------------------------------------------------------------------------------------------------------------------------------------------|-----------|-----|---|-----|-----|
| Current–Gain — Bandwidth Product<br>( $I_C = 10\text{ mA}$ , $V_{CE} = 5.0\text{ Vdc}$ , $f = 100\text{ MHz}$ )                                     | $f_T$     | 100 | — | —   | MHz |
| Output Capacitance ( $V_{CB} = 10\text{ V}$ , $f = 1.0\text{ MHz}$ )                                                                                | $C_{obo}$ | —   | — | 4.5 | pF  |
| Noise Figure ( $I_C = 0.2\text{ mA}$ ,<br>$V_{CE} = 5.0\text{ Vdc}$ , $R_S = 2.0\text{ k}\Omega$ ,<br>$f = 1.0\text{ kHz}$ , $BW = 200\text{ Hz}$ ) | NF        |     |   |     | dB  |
| LBC846A, LBC846B, LBC847B, LBC848B                                                                                                                  |           | —   | — | 10  |     |
| LBC847C, LBC848C                                                                                                                                    |           | —   | — | 4.0 |     |

## LBC846ADW1T1G Series

### TYPICAL CHARACTERISTICS



## LBC846ADW1T1G Series

### TYPICAL CHARACTERISTICS

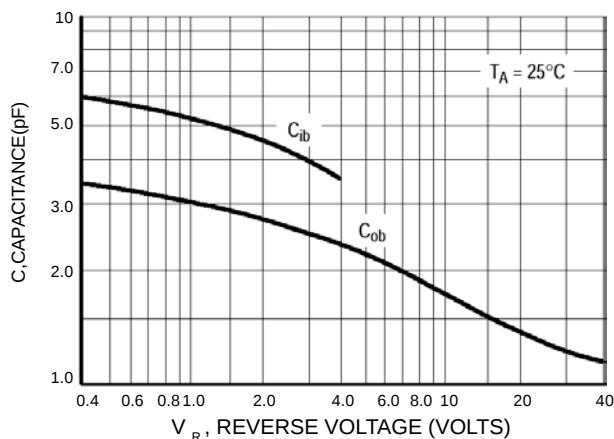


Figure 5. Capacitances

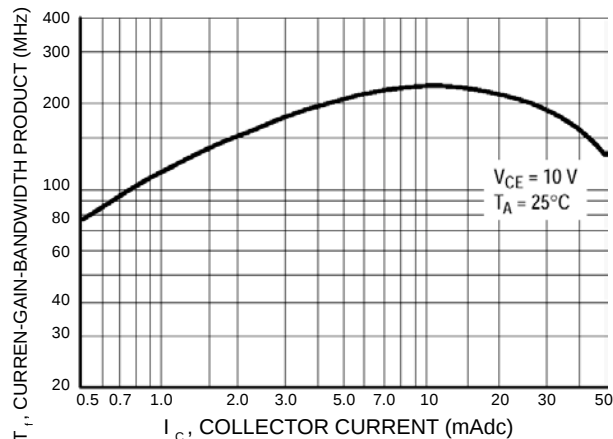


Figure 6. Current-Gain - Bandwidth Product

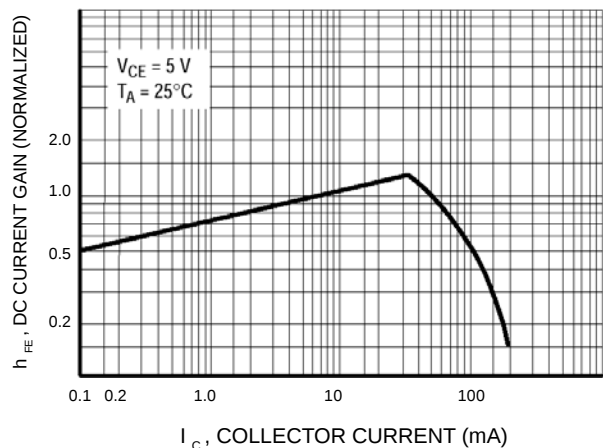


Figure 7. DC Current Gain

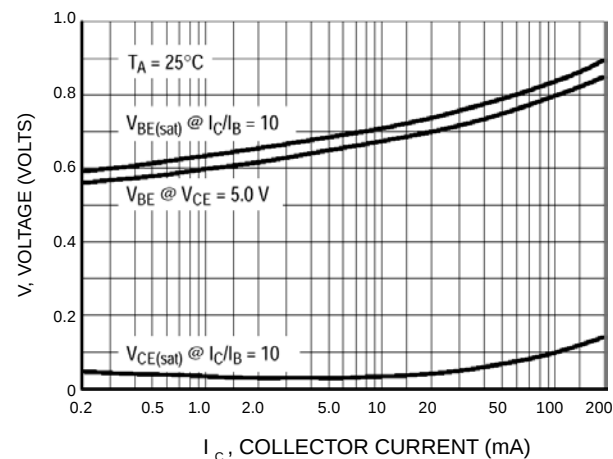


Figure 8. "On" Voltage

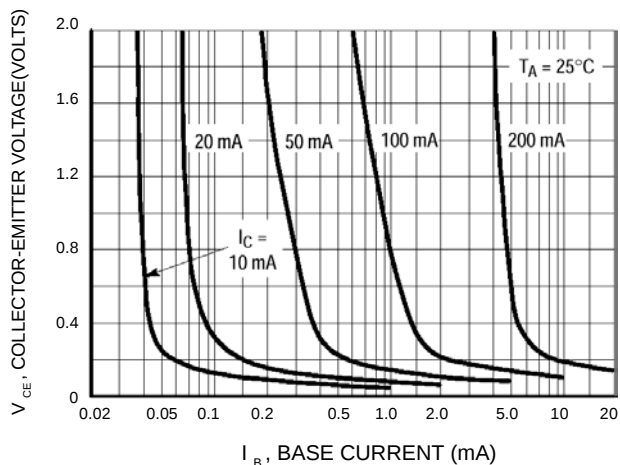


Figure 9. Collector Saturation Region

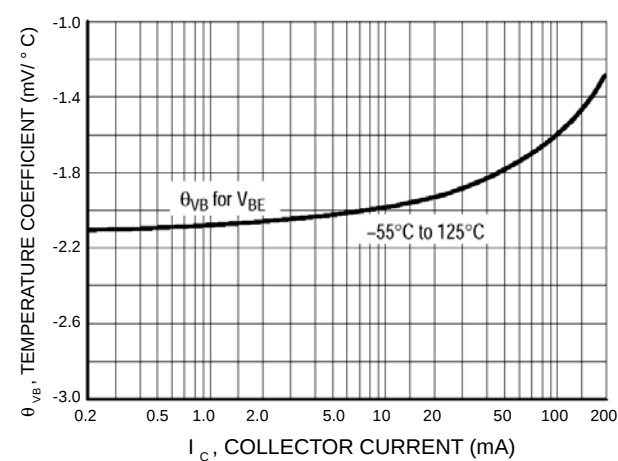


Figure 10. Base-Emitter Temperature Coefficient

## LBC846ADW1T1G Series

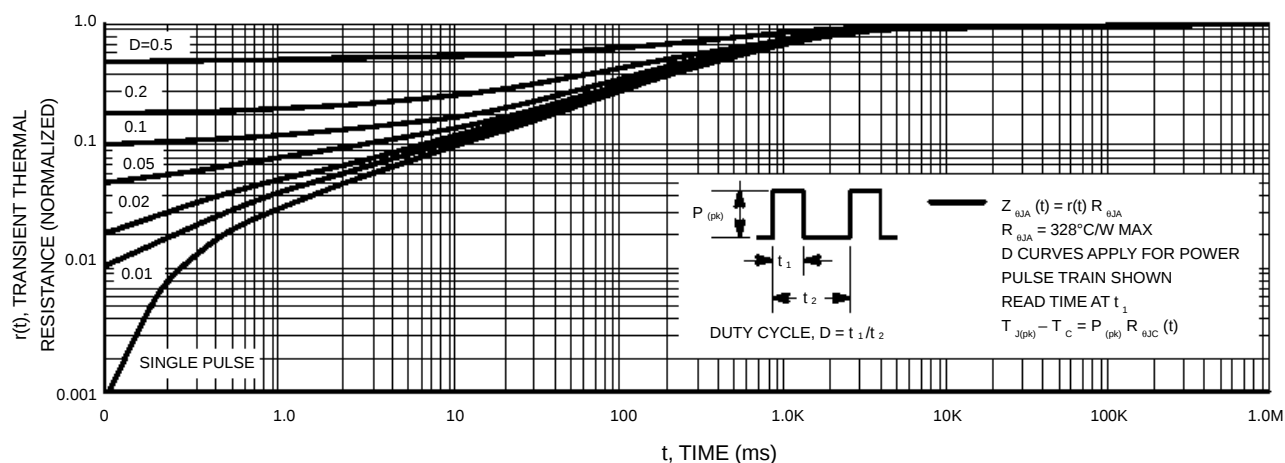


Figure 11. Thermal Response

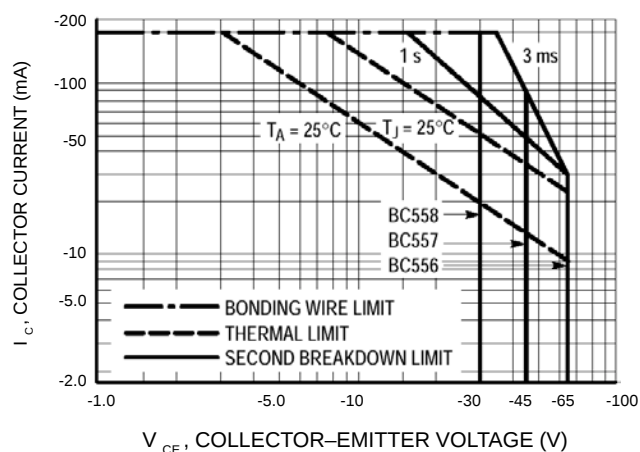


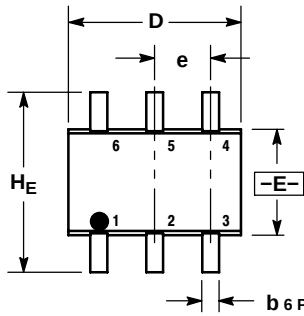
Figure 12. Active Region Safe Operating Area

The safe operating area curves indicate  $I_C$ - $V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

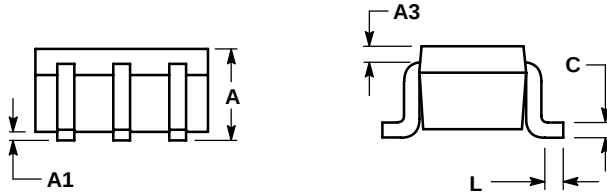
The data of Figure 12 is based upon  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  or  $T_A$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 12. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

## LBC846ADW1T1G Series

SC-88



|          |             |   |   |   |
|----------|-------------|---|---|---|
| $\oplus$ | 0.2 (0.008) | M | E | M |
|----------|-------------|---|---|---|

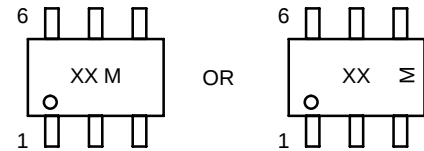


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

| DIM | MILLIMETERS |      |      | INCHES    |       |       |
|-----|-------------|------|------|-----------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN       | NOM   | MAX   |
| A   | 0.80        | 0.95 | 1.10 | 0.031     | 0.037 | 0.043 |
| A1  | 0.00        | 0.05 | 0.10 | 0.000     | 0.002 | 0.004 |
| A3  | 0.20 REF    |      |      | 0.008 REF |       |       |
| b   | 0.10        | 0.21 | 0.30 | 0.004     | 0.008 | 0.012 |
| C   | 0.10        | 0.14 | 0.25 | 0.004     | 0.005 | 0.010 |
| D   | 1.80        | 2.00 | 2.20 | 0.070     | 0.078 | 0.086 |
| E   | 1.15        | 1.25 | 1.35 | 0.045     | 0.049 | 0.053 |
| e   | 0.65 BSC    |      |      | 0.026 BSC |       |       |
| L   | 0.10        | 0.20 | 0.30 | 0.004     | 0.008 | 0.012 |
| HE  | 2.00        | 2.10 | 2.20 | 0.078     | 0.082 | 0.086 |

### GENERIC MARKING DIAGRAM\*



XX = Specific Device Code  
M = Date Code